

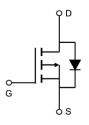
60V P-Channel Enhancement Mode MOSFET

• General Description

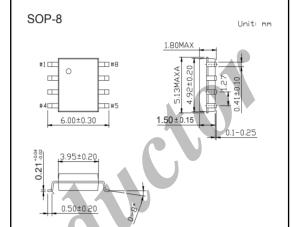
AP4421 combines advanced MOSFET technology with a low resistance package to provide extremely low $R_{DS(\text{ON})}$. This device is most suitable to load-switch or PWM applications.

Applications

- DC-DC converter for portable devices
- Load switch









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Product Summary

Vds	-60V
In (at $V_{GS} = -10V$)	-6.2A
$R_{DS(ON)}$ (at $V_{GS} = -10V$)	$< 40 \mathrm{m}\Omega$
RDS(ON) (at $V_{GS} = -4.5V$)	< 50mΩ

Absolute Maximum Ratings Ta = 25°C

Parameter		Symbol	Rating	Unit	
Drain-Source Voltage		V_{DS}	-60	V	
Gate-Source Voltage		V_{GS}	±20	V	
Continuous Drain Current	Ta = 25°C	I_D	-6.2		
	Ta = 70°C		-5.0	Α	
Pulsed Drain Current		I_{DM}	-40		
Power Dissipation	Ta = 25°C	P_D	3.1	W	
	Ta = 70°C		2	VV	
Junction and Storage Temperature Range		T_J , T_{STG}	-55 to 150	°C	
Thermal Characteristics					
Thermal Resistance. Junction-to-Ambient	t ≤ 10s	$R_{ heta JA}$	40		
	Steady State	ТОЛА	75	°C/W	
Thermal Resistance. Junction-to-Lead	Steady State	$R_{\theta JL}$	30		



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• Electrical Characteristics Ta = 25°C

Parameter	Symbol	Test Conditions	Min	Тур	Max	Unit
Static Parameters						P
Drain-Source Breakdown Voltage	V_{DSS}	I _D =-250μA, V _{GS} =0V	-60			V
Zero Gate Voltage Drain Current	_	V _{DS} =-48V, V _{GS} =0V			-1	
	I_{DSS}	V_{DS} =-48V, V_{GS} =0V, T_{J} =55°C		K	-5	μΑ
Gate-Body Leakage Current	I_{GSS}	V _{DS} =0V, V _{GS} =±20V			±100	nA
Gate Threshold Voltage	V _{GS(th)}	$V_{DS}=V_{GS}$, $I_{D}=-250\mu A$	-1		-3	V
On-State Drain Current	I _{D(ON)}	V _{GS} =-10V, V _{DS} =-5V	-40			A
Static Drain-Source On-Resistance		V _{GS} =-10V, I _D =-6.2A			40	
	R _{DS(ON)}	V_{GS} =-10V, I_D =-6.2A, T_J =125°C			70	$m\Omega$
		V_{GS} =-4.5V, I_D =-5A	V		50	
Forward Transconductance	$\mathbf{g}_{ ext{FS}}$	V_{DS} =-5V, I_{D} =-6.2A		18		S
Diode Forward Voltage	V_{SD}	I _S =-1A, V _{GS} =0V			-1	V
Maximum Body-Diode Continuous Current	I_S				-4.2	Α
Dynamic Parameters						
Input Capacitance	C_{iss}			2417	2900	
Output Capacitance	C_{oss}	V_{GS} =0V, V_{DS} =-30V, f=1MHz		179		pF
Reverse Transfer Capacitance	C_{rss}			120		
Gate Resistance	Rg	V _{GS} =0V, V _{DS} =0V, f=1MHz		1.9	2.3	Ω
Switching Parameters						
Total Gate Charge (10V)				46.5	55	
Total Gate Charge (4.5V)	Qg	V - 10V V - 20V I - 62A		22.7		nC
Gate Source Charge	$Q_{\rm gs}$	V_{GS} =-10V, V_{DS} =-30V, I_{D} =-6.2A		9.1		
Gate Drain Charge	Q_{gd}			9.2		
Turn-On Delay Time	t _{D(on)}			9.8		
Turn-On Rise Time	t _r	V_{GS} =-10V, V_{DS} =-30V, R_{L} =4.7 Ω ,		6.1		
Turn-Off Delay Time	$t_{\mathrm{D(off)}}$	$R_{GEN}=3\Omega$		44		ns
Turn-Off Fall Time	t_{f}			12.7		
Body Diode Reverse Recovery Time	t_{rr}	I_F =-6.2A, d_i/d_t =100A/ μ s		34	42	
Body Diode Reverse Recovery Charge	Q_{rr}	I_F =-6.2A, d_i/d_t =100A/ μ s		47		nC

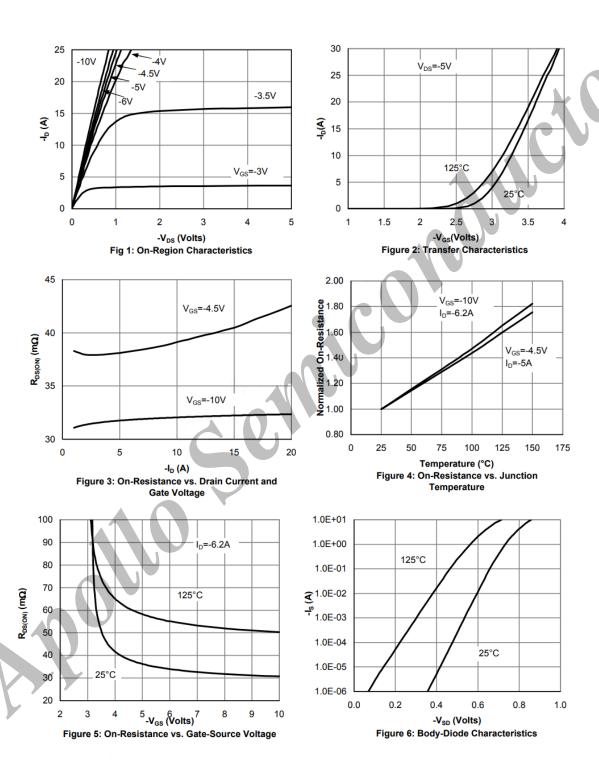
Ordering Information

Ordering Part Number	Package	MOQ
AP4421	SOP-8	2,500 pcs / reel

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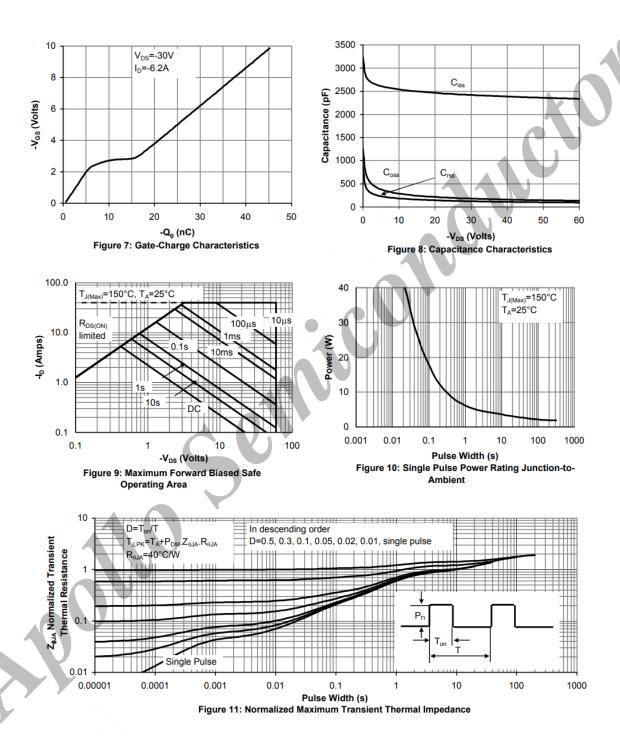


• Typical Electrical and Thermal Characteristics





• Typical Electrical and Thermal Characteristics





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